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Data Sheet

September 2013

N-Channel Power MOSFET 50V, 16A, 47 mΩ

The RFD16N05 and RFD16N05SM N-channel power MOSFETs are manufactured using the MegaFET process. This process, which uses feature sizes approaching those of LSI integrated circuits, gives optimum utilization of silicon, resulting in outstanding performance. They were designed for use in applications such as switching regulators, switching converters, motor drivers, and relay drivers. These transistors can be operated directly from integrated circuits.

Formerly developmental type TA09771.

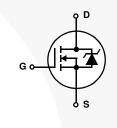
Ordering Information

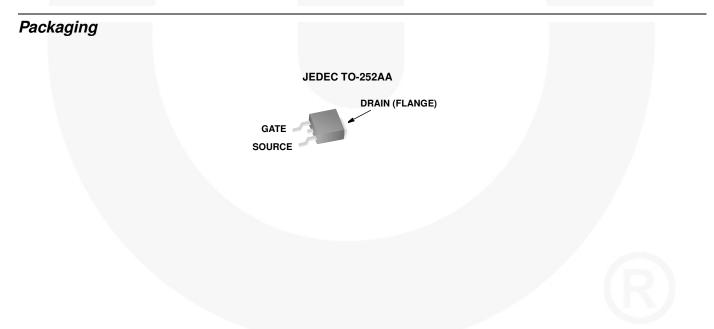
PART NUMBER	PACKAGE	BRAND	
RFD16N05SM9A	TO-252AA	D16N05	

Features

- 16A, 50V
- r_{DS(ON)} = 0.047Ω
- Temperature Compensating PSPICE[®] Model
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- 175⁰C Operating Temperature
- Related Literature
 - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards"

Symbol





Absolute Maximum Ratings $T_{C} = 25^{\circ}C$, Unless Otherwise Specified

	RFD16N05SM9A	UNITS
Drain to Source Voltage (Note 1) V _{DSS}	50	V
Drain to Gate Voltage (Note 1)	50	V
Continuous Drain Current I _D	16	А
Pulsed Drain Current (Note 3)	Refer to Peak Current Curve	
Gate to Source VoltageV _{GS}	±20	V
Pulsed Avalanche RatingE _{AS}	Refer to Figure 5	
Power Dissipation	72	W
Derate above 25°C	0.48	W/ ^o C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10s	300	°C
Package Body for 10s, See Techbrief 334	260	oC

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

PARAMETER	SYMBOL	TEST	CONDITIONS	MIN	ТҮР	MAX	UNITS
Drain to Source Breakdown Voltage	BV _{DSS}	$I_{D} = 250 \mu A, V_{GS} = 0$	V (Figure 11)	50	-	-	V
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D} = 250$	μΑ	2	-	4	V
Zero Gate Voltage Drain Current	IDSS	V_{DS} = Rated BV _{DSS} , V_{GS} = 0V		-	-	1	μA
		$V_{DS} = 0.8 \text{ x} \text{ Rated BV}_{DSS}, V_{GS} = 0 \text{V},$ $T_{C} = 150^{\circ}\text{C}$		-	-	25	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±20V		-	-	±100	nA
Drain to Source On Resistance (Note 2)	rDS(ON)	I _D = 16A, V _{GS} = 10V	(Figure 9)	-	-	0.047	Ω
Turn-On Time	t _(ON)	$V_{DD} = 25V, I_D = 8A, R_L = 3.125\Omega, V_{GS} = 10V, R_{GS} = 25\Omega$ (Figure 13)		-	-	65	ns
Turn-On Delay Time	t _{d(ON)}			-	14	-	ns
Rise Time	t _r			-	30	-	ns
Turn-Off Delay Time	t _{d(OFF)}			-	55	-	ns
Fall Time	t _f			/ -	30	-	ns
Turn-Off Time	t(OFF)			-	-	125	ns
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V$ to 20V	$V_{DD} = 40V, I_D \approx 16A,$	-	-	80	nC
Gate Charge at 10V	Q _{g(10)}	$V_{GS} = 0V$ to $10V$	$R_{L} = 2.5\Omega$ $I_{g(REF)} = 0.8mA$	-	-	45	nC
Threshold Gate Charge	Q _(TH)	$V_{GS} = 0V$ to 2V	(Figure 13)	-	-	2.2	nC
Input Capacitance	C _{ISS}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz (Figure 12)		-	900	-	pF
Output Capacitance	C _{OSS}			-	325	-	pF
Reverse Transfer Capacitance	C _{RSS}			- /	100	-	pF
Thermal Resistance Junction to Case	R _{θJC}			-	-	2.083	°C/W
Thermal Resistance Junction to Ambient	R _{0JA}	TO-251 and TO-252		-	-	100	°C/W

Electrical Specifications T_C = 25°C, Unless Otherwise Specified

Source to Drain Diode Specifications

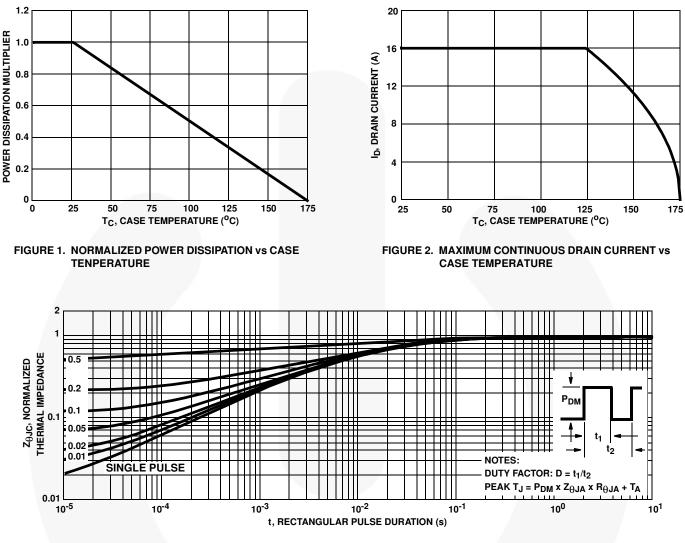
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Source to Drain Diode Voltage	V _{SD}	I _{SD} = 16A	-	-	1.5	V
Diode Reverse Recovery Time	t _{rr}	I_{SD} = 16A, dI _{SD} /dt = 100A/µs	-	-	125	ns

NOTES:

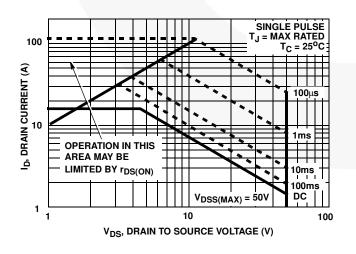
2. Pulse test: pulse width $\leq 250 \mu s$, duty cycle $\leq \%$.

3. Repetitive rating: pulse width limited by maximum junction temperature. See Transient Thermal Impedance curve (Figure 3) and Peak Current Capability Curve (Figure 5).

Typical Performance Curves Unless Otherwise Specified









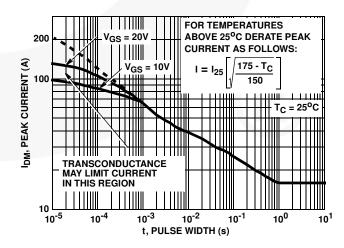
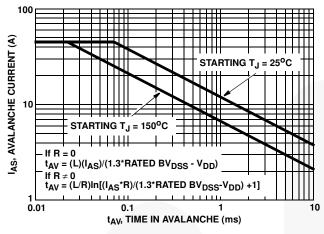


FIGURE 5. PEAK CURRENT CAPABILITY

Typical Performance Curves Unless Otherwise Specified (Continued)



NOTE: Refer to Fairchild Application Notes AN9321 and AN9322. FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING

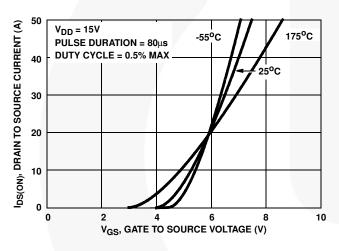
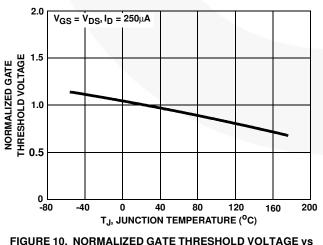
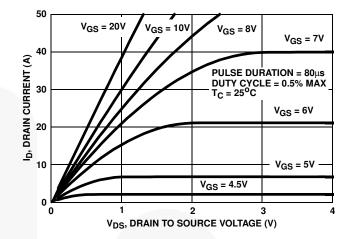


FIGURE 8. TRANSFER CHARACTERISTICS









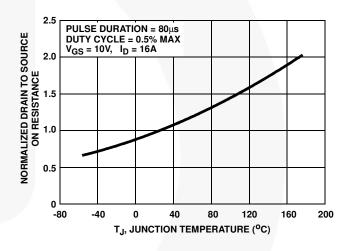
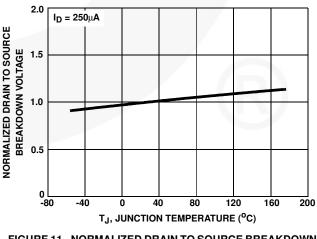


FIGURE 9. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE





Typical Performance Curves Unless Otherwise Specified (Continued)

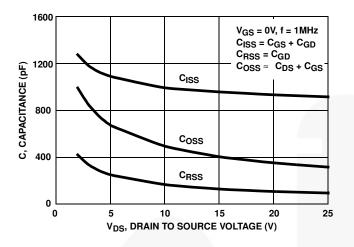
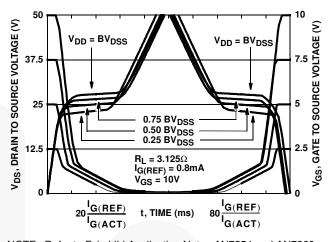


FIGURE 12. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260. FIGURE 13. NORMALIZED SWITCHING WAVEFORMS FOR CONSTANT GATE CURRENT

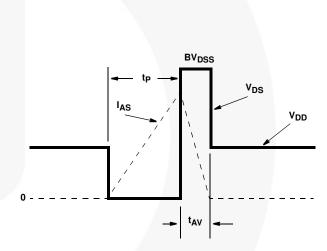


FIGURE 15. UNCLAMPED ENERGY WAVEFORMS

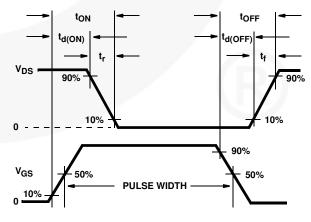


FIGURE 17. RESISTIVE SWITCHING WAVEFORMS

Test Circuits and Waveforms

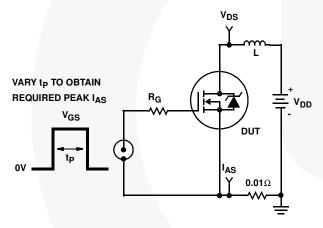


FIGURE 14. UNCLAMPED ENERGY TEST CIRCUIT

V_{GS}

₹ r_{gs}

FIGURE 16. SWITCHING TIME TEST CIRCUIT

VDS

 R_L

DUT

VDD

VGS

Test Circuits and Waveforms (Continued)

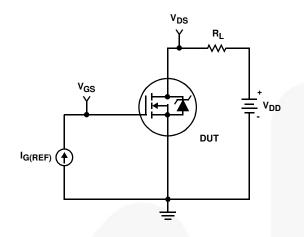
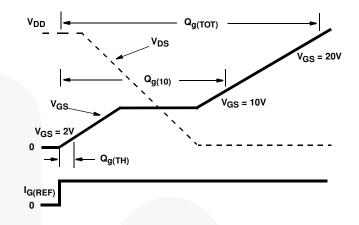


FIGURE 18. GATE CHARGE TEST CIRCUIT

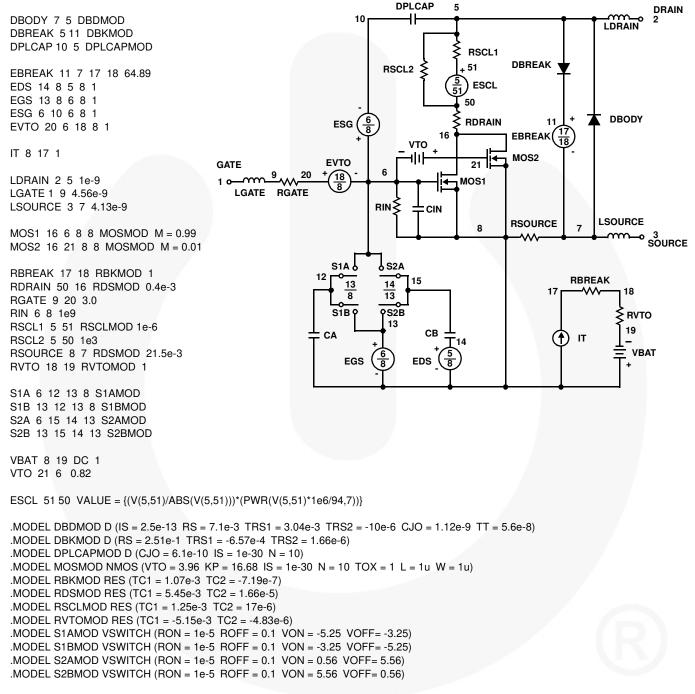




PSPICE Electrical Model

.SUBCKT RFD16N05 2 1 3; rev 10/31/94

CA 12 8 1.788e-10 CB 15 14 1.875e-10 CIN 6 8 8.33e-10



.ENDS

NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options**; written by William J. Hepp and C. Frank Wheatley.



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